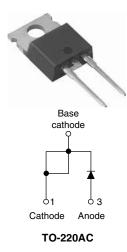
Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 25 A



PRODUCT SUMMARY				
V _R	600 V			
V _F at 25 A at 25 °C	1.7 V			
I _{F(AV)}	25 A			
t _{rr} (typical)	23 ns			
T _J (maximum)	150 °C			
Q _{rr} (typical)	112 nC			
dl _{(rec)M} /dt (typical)	250 A/µs			
I _{BBM}	10 A			

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- Lead (Pb)-free
- Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA25TB60 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A continuous current, the HFA25TB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA25TB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		600	V	
Maximum continuous forward current	١ _F	T _C = 100 °C	25		
Single pulse forward current	I _{FSM}		225	А	
Maximum repetitive forward current	I _{FRM}		100		
Movimum power dissinction	P _D	T _C = 25 °C	125	W	
Maximum power dissipation		T _C = 100 °C	50	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

* Pb containing terminations are not RoHS compliant, exemptions may apply





HFA25TB60PbF



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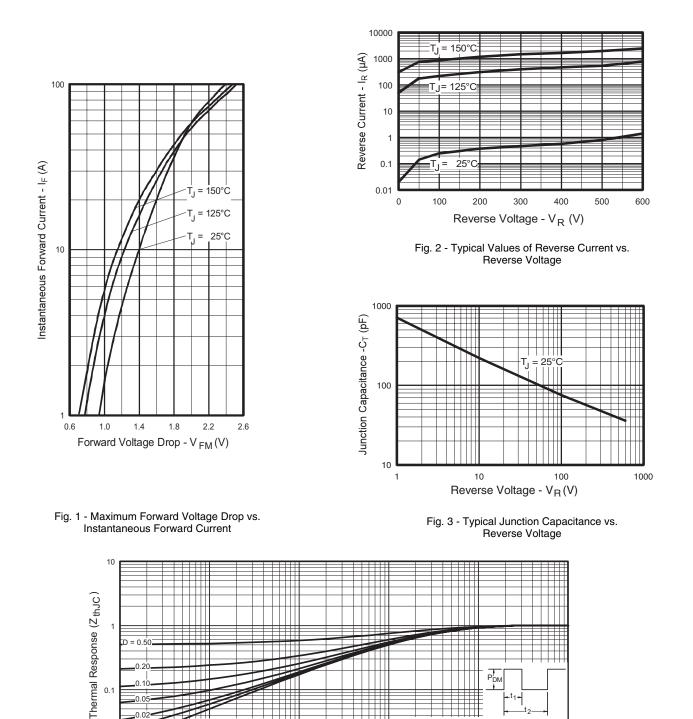
ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
		I _F = 25 A		-	1.3	1.7	v
Maximum forward voltage	um forward voltage V _{FM}	I _F = 50 A	See fig. 1	-	1.5	2.0	
		I _F = 25 A, T _J = 125 °C		-	1.3	1.7	
Maximum reverse		V _R = V _R rated	Coofin 0	-	1.5	20	
leakage current	I _{RM}	$T_J = 125 \ ^{\circ}C, V_R = 0.8 \ x \ V_R$ rated	See fig. 2	-	600	2000	μΑ
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	55	100	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 -		-	nH		

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
.	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	23	-	
Reverse recovery time See fig. 5, 6 and 16	t _{rr1}	T _J = 25 °C	-	-	50	75	ns
	t _{rr2}	T _J = 125 °C		-	105	160	
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	4.5	10	А
See fig. 7 and 8	ee fig. 7 and 8 I _{RRM2} T _J = 125 °C I _F = 25 A	I _F = 25 A	-	8.0	15	A	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C	dl _F /dt = 200 A/μs V _R = 200 V	-	112	375	nC
See fig. 9 and 10	Q _{rr2}	T _J = 125 °C		-	420	1200	
Peak rate of fall of recover curent during t _h	dl _{(rec)M} /dt1	T _J = 25 °C		-	250	-	A/µs
See fig. 11 and 12	dl _{(rec)M} /dt2	$T_J = 125 \ ^\circ C$		-	160	-	-7,μ5

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	1.0	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)
Marking device		Case style TO-220AC		HFA2	5TB60	



Vishay High Power Products **HEXFRED[®]** Ultrafast Soft Recovery Diode, 25 A



0.02

0.01

0.01

SINGLE PULSE

0.0001

(THERMAL RESPONSE

t1, Rectangular Pulse Duration (sec) Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

0.001

Notes

0.01

1. Duty factor D =t₁ / t₂ 2. Peak T_J=P _{DM} x Z_{thJC}

0.1

TC

HFA25TB60PbF

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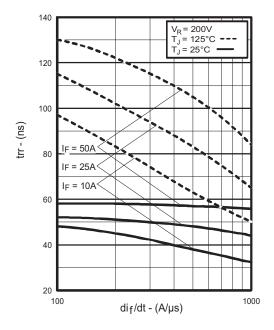
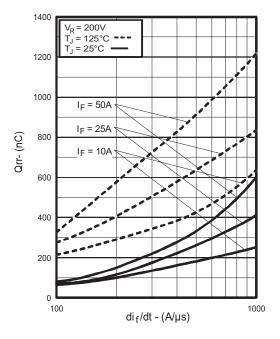


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt



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Fig. 7 - Typical Stored Charge vs. $dI_{\rm F}/dt$

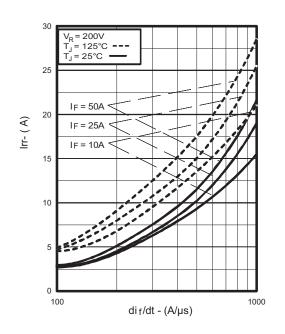


Fig. 6 - Typical Recovery Current vs. dl_F/dt

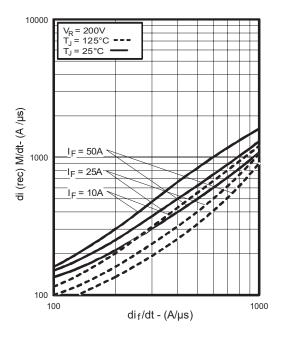


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt



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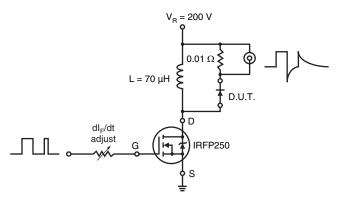


Fig. 9 - Reverse Recovery Parameter Test Circuit

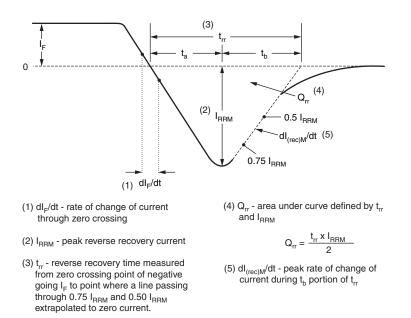


Fig. 10 - Reverse Recovery Waveform and Definitions

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95221				
Part marking information	http://www.vishay.com/doc?95224			



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